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RFMD(R) Announces Availability of New pHEMT Process Technologies for Foundry Customers

GREENSBORO, N.C., July 19, 2011 (GLOBE NEWSWIRE) -- RF Micro Devices, Inc. (Nasdaq:RFMD), a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies, today announced its Foundry Services business unit has expanded its portfolio of process technologies to include two additional GaAs process technologies — RFMD's FD25 low noise pHEMT process and RFMD's FET1H switching pHEMT process. The two additional GaAs pHEMT process technologies are available immediately to foundry customers.

RFMD's 0.25-micron FD25 pHEMT process technology delivers low noise, medium power and high linearity for applications including low noise front ends and transmitter MMICs. RFMD's 0.6-micron FET1H pHEMT process technology delivers low noise and high linearity switching of RF signals for applications including wireless front ends, transmit/receive modules and phased arrays.

The two new process technologies complement RFMD's existing 0.3-micron FD30 pHEMT process technology, which was made available to foundry customers in 2010 and is optimized for applications including X-band phased array power amplifiers and 8-16 GHz wideband military EW jammers.

The rapid growth in the wireless communications, aerospace and defense, and radar/radar jammer markets continues throughout the world, driven by end applications requiring the higher levels of integration enabled by leading semiconductor technologies. This increases the need for semiconductor foundries to develop and offer world-class technologies with flexible high performance capabilities. RFMD's low noise FD25 and high linearity switch FET1H technologies, along with RFMD's existing FD30 0.3-micron power process technology, offer customers the ability to design and manufacture world-class devices for a wide range of application needs.

Bob Van Buskirk, president of RFMD's Multi-Market Products Group (MPG), said, "Our FD25 0.25-micron and FET1H 0.6-micron processes further expand on our goal to provide the wireless industry a technically advanced semiconductor foundry service offering. We are pleased to expand and grow our foundry services business beyond our current GaN and GaAs offerings to assist our customers in meeting their individual market and product needs."

More information on RFMD's foundry services can be obtained by contacting RFMDFoundryServices@rfmd.com.

About RFMD

RF Micro Devices, Inc. (Nasdaq:RFMD) is a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies. RFMD's products enable worldwide mobility, provide enhanced connectivity and support advanced functionality in the cellular handset, wireless infrastructure, wireless local area network (WLAN), CATV/broadband and aerospace and defense markets. RFMD is recognized for its diverse portfolio of semiconductor technologies and RF systems expertise and is a preferred supplier to the world's leading mobile device, customer premises and communications equipment providers.

Headquartered in Greensboro, N.C., RFMD is an ISO 9001- and ISO 14001-certified manufacturer with worldwide engineering, design, sales and service facilities. RFMD is traded on the NASDAQ Global Select Market under the symbol RFMD. For more information, please visit RFMD's web site at www.rfmd.com.

The RF Micro Devices, Inc. logo is available at <http://www.globenewswire.com/newsroom/prs/?pkgid=6436>

This press release includes "forward-looking statements" within the meaning of the safe harbor provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements include, but are not limited to, statements about our plans, objectives, representations and contentions and are not historical facts and typically are identified by use of terms such as "may," "will," "should," "could," "expect," "plan," "anticipate," "believe," "estimate," "predict," "potential," "continue" and similar words, although some forward-looking statements are expressed differently. You should be aware that the forward-looking statements included herein represent management's current judgment and expectations, but our actual results, events and performance could differ materially from those expressed or implied by forward-looking statements. We do not intend to update any of these forward-looking statements or publicly announce the results of any revisions to these forward-looking statements, other than as is required under the federal securities laws. RF Micro Devices' business is subject to numerous risks and

uncertainties, including variability in operating results, risks associated with the impact of global macroeconomic and credit conditions on our business and the business of our suppliers and customers, our reliance on a few large customers for a substantial portion of our revenue, the rate of growth and development of wireless markets, our ability to bring new products to market, our reliance on inclusion in third party reference designs for a portion of our revenue, our ability to manage channel partner and customer relationships, risks associated with the operation of our wafer fabrication, molecular beam epitaxy, assembly and test and tape and reel facilities, our ability to complete acquisitions and integrate acquired companies, including the risk that we may not realize expected synergies from our business combinations, our ability to attract and retain skilled personnel and develop leaders, variability in production yields, raw material costs and availability, our ability to reduce costs and improve margins in response to declining average selling prices, our ability to adjust production capacity in a timely fashion in response to changes in demand for our products, dependence on gallium arsenide (GaAs) for the majority of our products, dependence on third parties, and substantial reliance on international sales and operations. These and other risks and uncertainties, which are described in more detail in RF Micro Devices' most recent Annual Report on Form 10-K and other reports and statements filed with the Securities and Exchange Commission, could cause actual results and developments to be materially different from those expressed or implied by any of these forward-looking statements.

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